

Notice of References Cited	Application/Control No. 10/644,803	Applicant(s)/Patent Under Reexamination EBE ET AL.	
	Examiner William M. Brewster	Art Unit 2823	Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-			
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FOREIGN PATENT DOCUMENTS

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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	"Effect of GaNAs Stain Compensatin Layer over InAs Quantum Dots Grown by MOMBE", Sasikala Ganapathy et al., Indium Phosphide and Related Materials Conference, 2002, IPRM. 14 TH , 12-16 May 2002, pp. 557-60.
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
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